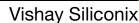
SPICE Device Model SiR846ADP





N-Channel 100 V (D-S) MOSFET

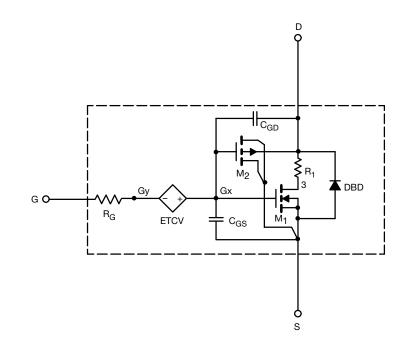
DESCRIPTION

The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the - $55 \,^{\circ}$ C to 125 $^{\circ}$ C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge



SUBCIRCUIT MODEL SCHEMATIC

Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

S13-1353-Rev. C, 10-Jun-13



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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	2.3	-	V
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	0.0065	0.0065	Ω
		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 15 \text{ A}$	0.0078	0.0076	
Forward Transconductance ^a	g _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	61	63	S
Body Diode Voltage	V _{SD}	I _S = 5 A	0.74	0.75	V
Dynamic ^b					
Input Capacitance	C _{iss}	V_{DS} = 50 V, V_{GS} = 0 V, f = 1 MHz	2350	2350	pF
Output Capacitance	C _{oss}		618	650	
Reverse Transfer Capacitance	C _{rss}		66	59	
Total Gate Charge	Qg	$V_{DS} = 50 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	41	44	nC
			23	26.7	
Gate-Source Charge	Q _{gs}	V_{DS} = 50 V, V_{GS} = 4.5 V, I_{D} = 20 A	8.2	8.2	
Gate-Drain Charge	Q _{gd}		9.2	9.2	

Notes

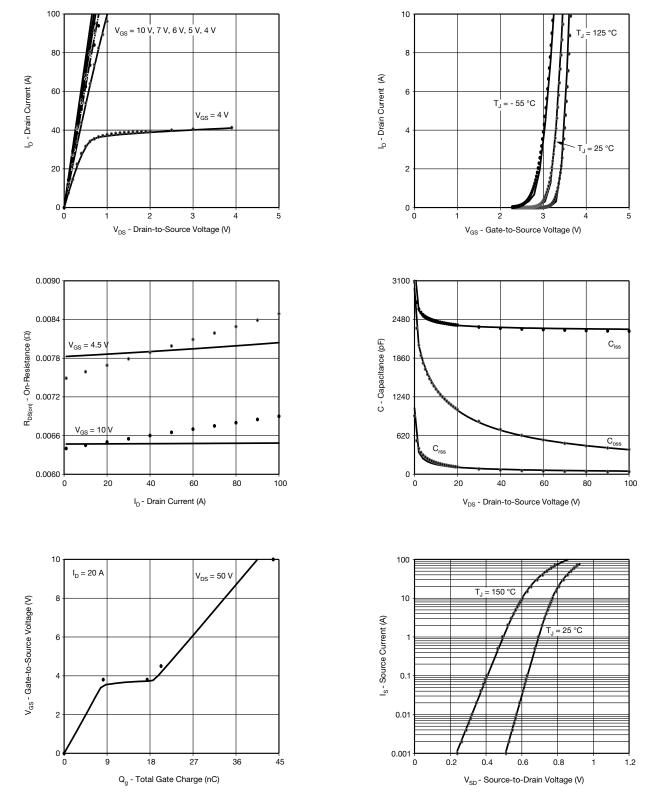
a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$

b. Guaranteed by design, not subject to production testing.



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COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C, unless otherwise noted)



Note

• Dots and squares represent measured data.

S13-1353-Rev. C, 10-Jun-13

3

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